查询RO2065供应商

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# #RII#"IM

Designed for 433.92 MHz Superhet Receiver LOs

Rating

- Low Series Resistance
- Quartz Stability
- Rugged, Hermetic, Low-Profile TO39 Case

The RO2065 is a true one-port, surface-acoustic-wave (SAW) resonator in a low-profile TO39 case. It provides reliable fundamental-mode quartz frequency stabilization, of fixed frequency oscillators operating at 433.92 MHz. The RO2065 is designed specifically for local oscillator in superhet receivers operating at 433.92 MHz for use in Germany under FTZ 17 TR2100. However, it is suitable for a variety of oscillator applications.



# 423.270 MHz SAW Resonator



CW RF Power Dissipation	+5	dBm
DC Voltage Between Terminals (Observe ESD Precautions)	±30	VDC
Case Temperature	-40 to +85	°C

#### **Electrical Characteristics**

**Absolute Maximum Ratings** 

CI	haracteristic	Sym	Notes	Minimum	Typical	Maximum	Units
Frequency (+25 °C)	Nominal Frequency	f <sub>C</sub>	2245	423.170		423.370	MHz
	Tolerance from 423.270 MHz	$\Delta f_{C}$	2, 3, 4, 5			±100	kHz
Insertion Loss		IL	2, 5, 6		2.8	7.0	dB
Quality Factor	Unloaded Q	QU	5, 6, 7		11,700	- 4- A 194	
	50 $\Omega$ Loaded Q	QL			3,200	COT	
Temperature Stability	Turnover Temperature	т <sub>о</sub>		27	42	57	°C
	Turnover Frequency	fo	6, 7, 8		f <sub>C</sub> +4.5		kHz
	Frequency Temperature Coefficient	FTC	30 14		0.037		ppm/°C <sup>2</sup>
Frequency Aging	Absolute Value during the First Year	fA	1, 6		10		ppm/yr
DC Insulation Resistance between Any Two Pins			5	1.0			MΩ
RF Equivalent RLC Model	Motional Resistance	R <sub>M</sub>			38	124	Ω
	Motional Inductance	L <sub>M</sub>	5, 6, 7, 9		167.175		μH
	Motional Capacitance	CM			.845734		fF
	Pin 1 to Pin 2 Static Capacitance	CO	5, 6, 9	1.9	2.2	2.5	pF
	Transducer Static Capacitance	CP	5, 6, 7, 9		2.0	TO TO T	pF
Test Fixture Shunt Inductance	ce	L <sub>TEST</sub>	2, 7	-	64		nH
Lid Symbolization (in addition	n to Lot and/or Date Codes)	or Date Codes) RFM RO2065					

Value

Units

#### CAUTION: Electrostatic Sensitive Device. Observe precautions for handling. Notes:

- Frequency aging is the change in f<sub>C</sub> with time and is specified at +65°C or less. Aging may exceed the specification for prolonged temperatures above +65°C. Typically, aging is greatest the first year after manufacture, decreasing significantly in subsequent years.
- 2. The center frequency,  $f_C$ , is measured at the minimum insertion loss point,  $IL_{MIN}$ , with the resonator in the 50  $\Omega$  test system (VSWR  $\leq$  1.2:1). The shunt inductance,  $L_{TEST}$ , is tuned for parallel resonance with  $C_O$  at  $f_C$ . Typically,  $f_{OSCILLA-TOR}$  or  $f_{TRANSMITTER}$  is less than the resonator  $f_C$ .
- One or more of the following United States patents apply: 4,454,488 and 4,616,197 and others pending.

Typically, equipment designs utilizing this device require emissions testing and government approval, which is the responsibility of the equipment manufacturer. Unless noted otherwise, case temperature  $T_c = +25^{\circ}C \pm 2^{\circ}C$ .

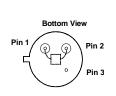
The design, manufacturing process, and specifications of this device are subject to change without notice.

- 7. Derived mathematically from one or more of the following directly measured parameters:  $f_C$ , IL, 3 dB bandwidth,  $f_C$  versus  $T_C$ , and  $C_O$ .
- 8. Turnover temperature, T<sub>O</sub>, is the temperature of maximum (or turnover) frequency, f<sub>O</sub>. The nominal frequency at any case temperature, T<sub>C</sub>, may be calculated from:  $f = f_O [1 FTC (T_O T_C)^2]$ . Typically, *oscillator* T<sub>O</sub> is 20°C less than the specified *resonator* T<sub>O</sub>.
- 9. This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance C<sub>O</sub> is the static (nonmotional) capacitance between pin1 and pin 2 measured at low frequency (10 MHz) with a capacitance meter. The measurement includes case parasitic capacitance with a floating case. For usual grounded case applications (with ground connected to either pin 1 or pin 2 and to the case), add approximately 0.25 pF to C<sub>O</sub>.

#### **Electrical Connections**

This one-port, two-terminal SAW resonator is bidirectional. The terminals are interchangeable with the exception of circuit board layout.

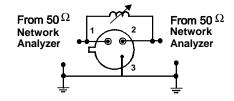
Pin	Connection		
1	Terminal 1		
2	Terminal 2		
3	Case Ground		



#### **Typical Test Circuit**

The test circuit inductor,  $L_{\text{TEST}},$  is tuned to resonate with the static capacitance,  $C_O$  at  $F_C.$ 

#### **Electrical Test:**



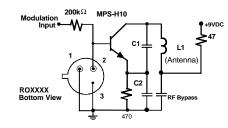
Power Test:



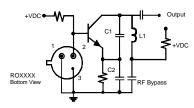
CW RF Power Dissipation = PINCIDENT PEFLECTED

### **Typical Application Circuits**

Typical Low-Power Transmitter Application:

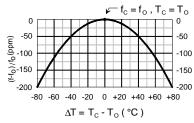


Typical Local Oscillator Application:



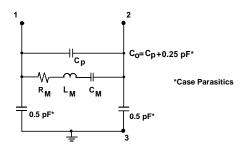
#### **Temperature Characteristics**

The curve shown on the right accounts for resonator contribution only and does not include oscillator temperature characteristics.

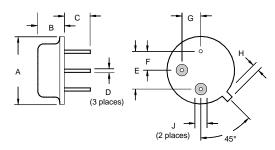


## Equivalent LC Model

The following equivalent LC model is valid near resonance:



#### **Case Design**



Dimensions	Millim	neters	Inches		
	Min	Max	Min	Max	
A		9.30		0.366	
В		3.18		0.125	
С	2.50	3.50	0.098	0.138	
D	0.46 Nominal		0.018 Nominal		
E	5.08 Nominal		0.200 Nominal		
F	2.54 Nominal		0.100 Nominal		
G	2.54 Nominal		0.100 Nominal		
Н		1.02		0.040	
J	1.40		0.055		